Unitized Semiconductor Devices - Page 1 of 1



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View Online at https://aerobasegroup.com/nsn/5961-01-567-2625	
Inclosure Material:	
Metal	
Overall Length:	
Between 0.650 inches and 0.935 inches	
Terminal Length:	
0.500 inches	
Overall Diameter:	
Between 0.335 inches and 0.370 inches	
End Application:	
Nsn 5821-01-387-0594; receiver-transmitter, radio	
Electrode Internally-electrically Connected To Case:	
Collector	
Component Name And Quantity:	
2 transistor	
Mounting Method:	
Terminal	
Terminal Circle Diameter:	
Between 0.190 inches and 0.210 inches	
Semiconductor Material:	
Silicon all transistor	
Voltage Rating In Volts Per Characteristic:	
60.0 collector to base voltage/static/emitter open all transistor and 60.0 collector to emitter voltage/static/base open all transistor and 5.0	
emitter to base voltage, static, collector open all transistor	
Current Rating Per Characteristic:	
50.00 milliamperes source cutoff current all transistor	
Power Rating Per Characteristic:	
0.6 watts small-signal input power, common-collector preset all transistor	
Maximum Operating Tempurature Per Measurement Point:	
200.0 degrees celsius junction	
Product Name:	
Transistor - pnp, dual amplifier	
Special Features:	
All transistor junction pattern arrangement: pnp	
Terminal Type And Quantity:	
6 uninsulated wire lead	
Shelf Life:	
N/a	
Unit Of Measure:	
Demilitarization:	
Fiig:	
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